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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/783,979	02/20/2004	Shintaro Asuke	9319S-000648	4405
	27572 7590 10/01/2007 HARNESS, DICKEY & PIERCE, P.L.C.		EXAMINER	
P.O. BOX 828		•	LAZORCIK, JASON L	
BLOOMFIELD HILLS, MI 48303		ART UNIT	PAPER NUMBER	
			1731	
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			10/01/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)
	10/783,979	ASUKE ET AL.
Office Action Summary	Examiner	Art Unit
	Jason L. Lazorcik	1731
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet w	th the correspondence address
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNION (186(a). In no event, however, may a control of the second will expire SIX (6) MON cause the application to become Af	CATION. eply be timely filed THS from the mailing date of this communication. IANDONED (35 U.S.C. § 133).
Status		
1)⊠ Responsive to communication(s) filed on 17 Ju 2a)□ This action is FINAL . 2b)⊠ This 3)□ Since this application is in condition for allowan closed in accordance with the practice under E	action is non-final. nce except for formal matt	·
Disposition of Claims		
4) ⊠ Claim(s) 1,2,4,6 and 8 is/are pending in the approach 4a) Of the above claim(s) is/are withdraw 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1,2,4,6 and 8 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and/or	vn from consideration.	
Application Papers		
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access applicant may not request that any objection to the objection drawing sheet(s) including the correction	epted or b) objected to drawing(s) be held in abeyar	nce. See 37 CFR 1.85(a).
11) The oath or declaration is objected to by the Ex	· · · · · · · · · · · · · · · · · · ·	
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list of	s have been received. s have been received in A ity documents have been ı (PCT Rule 17.2(a)).	pplication No received in this National Stage
· .		
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 6/25/2007.	Paper No(Summary (PTO-413) s)/Mail Date nformal Patent Application

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on July 17, 2007 has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

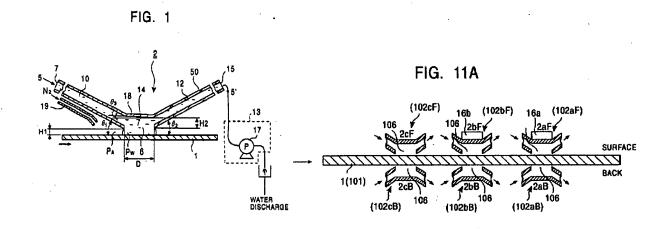
(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 4, 6 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Mitsumori (US 6,230,722 B1).

Mitsumori teaches a wet treatment method and apparatus for treatment of "large-sized substrates such as ... a substrate for liquid crystal" (Column 1, lines 14-17). As depicted in the instant reference figure 11A (see below). Mitsumori teaches that the substrate (1) is subjected continuous plural types of treatments wherein the substrate is selectively held above treatment units (2cB, 2bB, 2AB) with the surface targeted for

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treatment facing downward and said units operating upward. It is evident from the figure that excess liquid applied to the surface targeted for treatment is permitted to "fall away from the surface after being applied to the surface".



Mitsumori teaches several embodiments of "fluid saving type fluid feed nozzles" including a particular embodiment (see fig 1 excerpt above) which comprises an introducing path (10) and discharge path (12). The reference indicates that the angle of incidence between the introducing or discharge path and the substrate (1), θ_1 and θ_2 respectively, can each be varied between 0 and 90° (Column 14, lines 3-8). Where the discharge path or "recovery path" presents a θ_2 = 90°, the nozzle is understood to present a recovery path formed by an inclined end surface of the nozzle (18) and an opposite surface (e.g. discharge path (12) wall which is distal from introducing path (10)) which is perpendicular to the surface targeted for treatment (1).

Mitsumori teaches that a sensor measures the distance between the nozzle and the substrate and provides feedback measurements to an actuator which provides for a constant separation distance (H1) (Column 14, lines 35-51). From the foregoing, it is understood that the "top end surfaces" of the nozzle are "disposed with a predetermined gap from the surface targeted for treatment". Finally, the reference teaches that the nozzle includes a pressure controller(13) which "comprises a reduced pressure pump provided on the discharging port side (15) (Column 13, lines 16-17). The provision of a reduced pressure pump is understood to encompass Applicants embodiment wherein "the recovery path is evacuated to a pressure that is less than atmospheric pressure"

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- Considering objective evidence present in the application indicating obviousness or nonobviousness.

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Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over Mitsumori (US 6,230,722 B1) as applied to claim 1 under 35 USC 102(b), and further in view of Goodwin (US 5,324,155).

Mitsumori is silent regarding the structural details of the transport device and therefore fails to teach that the transport device described for transferring the substrate between treatment chambers should provide a suction portion to suction and hold the surface targeted for holding, which is opposite the surface targeted for treatment.

Mitsumori further fails to explicitly indicate that transport device (855) comprises a guide component for guiding the holding portion in the carrying direction and a driving portion for transferring the holding portion along the guide component. Goodwin teaches a wafer handling system including a pair of robot arms and a drive portion with a plurality of ports providing a lifting action for a substrate by utilizing the Bernoulli principle. The device provides "low pressure" or a suction between the device and the surface of the substrate without contacting the substrate. I

It would have been obvious to one of ordinary skill in the art at the time of the invention to utilize a handling system in accord with the Goodwin apparatus as the transport device in the Mitsumori process. This would have been an obvious substitution to anyone seeking to minimize the possibility of damaging a fragile substrate by direct contact with the handling system or transport device.

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Claims 1, 4, 6, and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakamura (US 6,921,148) in view of Mitsumori (US 6,230,722 B1).

With particular respect to Claims 1 and 6, Nakamura teaches a method of manufacturing the substrate of a display device wherein the substrate is selectively held by a carrier and carried along the carry direction (column 76, Lines 37-41) and through various process chambers wherein the object is subjected to sequential different treatments. As with any apparatus, the individual chambers may be disassembled and replaced at will.

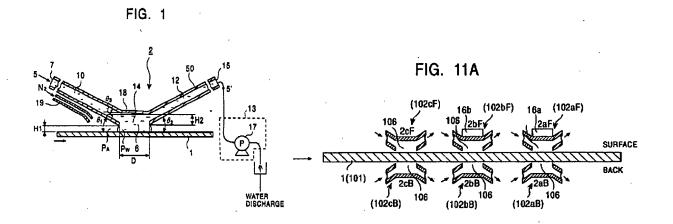
With respect to Claims 4 and 8, Nakamura teaches a plasma processing process (Column 76, Lines 7 to Column 80, Line13) which reads on the claimed cleaning treatment unit and surface modification treatment unit. The disclosed liquid drop discharge process (column 86line65 – Column 87, line12), the drying process (Column 87, line 42-43), and the heat processing step (Column 88, lines35-40) are understood to read upon the liquid agent application treatment unit, drying treatment unit, and annealing treatment unit, respectively.

While Nakamura sets forth the fundamental process steps in accord with the claimed invention and an apparatus for the performance of these steps, the reference fails to explicitly indicate that the treatment surface faces downward and that the treatment units are operated upward. Nakamura is further silent regarding the particular details of the cleaning treatment unit as presently claimed.

Mitsumori teaches a wet treatment method and apparatus for treatment of "largesized substrates such as ... a substrate for liquid crystal" (Column 1, lines 14-17) which

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one of ordinary skill would recognize as directly relevant to the Nakamura teachings. Mitsumori teaches a variety of "fluid saving type fluid feed nozzles" including a particular embodiment (see fig 1 excerpt below) which comprises an introducing path (10) and discharge path (12). The reference indicates that the angle of incidence between the introducing or discharge path and the substrate (1), θ_1 and θ_2 respectively, can each be varied between 0 and 90° (Column 14, lines 3-8). Where the discharge path or "recovery path" presents a θ_2 = 90°, the nozzle is understood to present a recovery path formed by an inclined end surface of the nozzle (18) and an opposite surface (e.g. discharge path (12) wall which is distal from introducing path (10)) which is perpendicular to the surface targeted for treatment (1).



Mitsumori teaches that a sensor measures the distance between the nozzle and the substrate and provides feedback measurements to an actuator which provides for a constant separation distance (H1) (Column 14, lines 35-51). From the foregoing, it is understood that the "top end surfaces" of the nozzle are "disposed with a predetermined gap from the surface targeted for treatment". Finally, the reference teaches that the

nozzle includes a pressure controller(13) which "comprises a reduced pressure pump provided on the discharging port side (15) (Column 13, lines 16-17). The provision of a reduced pressure pump is understood to encompass Applicants embodiment wherein "the recovery path is evacuated to a pressure that is less than atmospheric pressure"

As depicted in the instant reference Figure 11A, Mitsumori disclosed particular embodiments wherein the surface targeted for treatment faces downward and wherein the nozzle is operated to apply treatment in an upward facing direction. Further Mitsumori teaches that the disclosed nozzle provides substrate treatment with "under a tenth the conventional consumption, and allow to obtain a higher cleanliness than conventional one". In accordance with the Mitsumori disclosure, it would have been obvoius to one of ordinary skill in the art at the time of the invention to substitute the disclosed nozzle for that presented in the Nakamura reference. This modification would have been obvoius to one of ordinary skill in the art seeking to reduce reagent consumption and reduced substrate contamination.

Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over

Nakamura (US 6,921,148) and Mitsumori (US 6,230,722 B1) as applied to claim 1

above, and further in view of Goodwin (US 5,324,155). Nakamura is silent regarding
the structural details of the transport device and therefore fails to teach that the
transport device described for transferring the substrate between treatment chambers
should provide a suction portion to suction and hold the surface targeted for holding,
which is opposite the surface targeted for treatment. Nakamura further fails to explicitly

indicate that transport device (855) comprises a guide component for guiding the holding portion in the carrying direction and a driving portion for transferring the holding portion along the guide component. Goodwin teaches a wafer handling system including a pair of robot arms and a drive portion with a plurality of ports providing a lifting action for a substrate by utilizing the Bernoulli principle. The device provides "low pressure" or a suction between the device and the surface of the substrate without contacting the substrate. It would have been obvious to one of ordinary skill in the art at the time of the invention to utilize a handling system in accord with the Goodwin apparatus as the transport device in the Nakamura process. This would have been an obvious substitution to anyone seeking to minimize the possibility of damaging a fragile substrate by direct contact with the handling system or transport device.

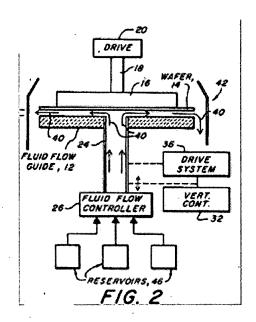
Claims 1, 2, 4, 6, and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cady (US 4,544,446) in view of Mitsumori (US 6,230,722 B1).

With particular reference to the instant reference figure 2 (see below), Cady teaches a treatment device for subjecting a surface of a substrate targeted for treatments to continuous plural types of treatments. Specifically, the reference teaches a substrate carrier (16) with treatment units (46).

As clearly depicted in the figure, the substrate surface targeted for treatment faces downward and the plural treatment units are operated upward to treat said targeted surface. A suction portion (16) or "vacuum chuck" holds a "surface targeted for holding" opposite the surface targeted for treatment and said suction portion is further

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interconnected with "a guide component" (18) and "a driving portion" (20) [Claim 2]. It is further evident that the fluid having been applied to the surface falls away (40) after having been applied to the surface.



With reference to the above figure, Cady sets forth that "it will be appreciated that the entire apparatus may be inverted such that the wafer is suspended from the top via vacuum chuck 16. The inverted system has the advantages of protecting the surface of the substrate from being contaminated by any particulates in the air falling from above, particularly during the loading and unloading steps. in addition, this configuration keeps all chemicals, and liquids and components in one location at the bottom of the reactor. Thus, during removal of the substrate, there is no accidental dripping of liquid on the newly cleansed or processed substrate. It will, of course, be appreciated that the chemicals must be placed under pressure in order to provide for the flow indicated by arrows 40." (Column 8, Lines 26-40)

The reference continues by teaching several processing steps widely recognized as conventional operations within the field of semiconductor processing. Specifically, Example 1 teaches wafer cleaning, Example 2 teaches a photoresist development step, Example 3 teaches a silica etching step, and Example 4 teaches a resist stripping step (Column 12, line 25 to Column 13, line 67). Although the reference indicates that "many of the above operations (e.g. Example 1 through 4) can be done sequentially without removal of the wafer (from the fluid flow guides)" it does not explicitly require separate treatment units arranged side by side "along a carrying direction of the substrate" as claimed.

To this end, it is the Examiners position that providing a separate treatment unit (e.g. fig 2) for each of the disclosed conventional processing operations (examples 1 to 4) would be a merely obvious extension over the Cady teachings for one having an ordinary level of skill in the art of automated semiconductor processing (e.g. casette-to-casette process equipment). Specifically, this modification would be an obvoius choice for anyone seeking to prevent cross contamination of sequential treatment fluids that may occur during sequential treatments in a single treatment unit. It would further be obvoius, absent any compelling and unexpected results to the contrary, for one of ordinary skill to arrange these separate treatment units in any manner deemed most to the end user including "along a carrying direction of the substrate".

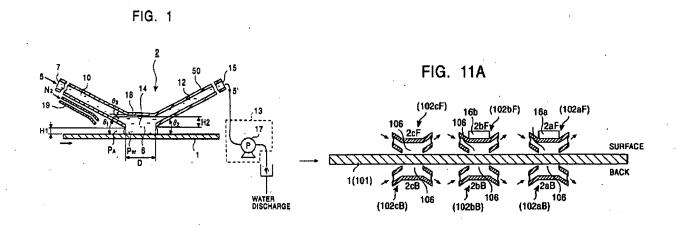
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While Cady sets forth the fundamental process steps in accord with the claimed invention and an apparatus for the performance of these steps, the reference fails to explicitly teach the particular details of the cleaning treatment unit as presently claimed.

Mitsumori teaches a wet treatment method and apparatus for treatment of "large-sized substrates such as ... a substrate for liquid crystal" (Column 1, lines 14-17) which one of ordinary skill would recognize as directly relevant to the Cady teachings. Mitsumori teaches a variety of "fluid saving type fluid feed nozzles" including a particular embodiment (see fig 1 excerpt below) which comprises an introducing path (10) and discharge path (12). The reference indicates that the angle of incidence between the introducing or discharge path and the substrate (1), θ_1 and θ_2 respectively, can each be varied between 0 and 90° (Column 14, lines 3-8). Where the discharge path or "recovery path" presents a θ_2 = 90°, the nozzle is understood to present a recovery path formed by an inclined end surface of the nozzle (18) and an opposite surface (e.g. discharge path (12) wall which is distal from introducing path (10)) which is perpendicular to the surface targeted for treatment (1).

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Mitsumori teaches that a sensor measures the distance between the nozzle and the substrate and provides feedback measurements to an actuator which provides for a constant separation distance (H1) (Column 14, lines 35-51). From the foregoing, it is understood that the "top end surfaces" of the nozzle are "disposed with a predetermined gap from the surface targeted for treatment". Finally, the reference teaches that the nozzle includes a pressure controller(13) which "comprises a reduced pressure pump provided on the discharging port side (15) (Column 13, lines 16-17). The provision of a reduced pressure pump is understood to encompass Applicants embodiment wherein "the recovery path is evacuated to a pressure that is less than atmospheric pressure"

As depicted in the instant reference Figure 11A, Mitsumori disclosed particular embodiments wherein the surface targeted for treatment faces downward and wherein the nozzle is operated to apply treatment in an upward facing direction. Further Mitsumori teaches that the disclosed nozzle provides substrate treatment with "under a tenth the conventional consumption, and allow to obtain a higher cleanliness than conventional one". In accordance with the Mitsumori disclosure, it would have been

obvoius to one of ordinary skill in the art at the time of the invention to substitute the disclosed fluid flow guide (12) in Cady with the "fluid saving feed nozzle" disclosed by Mitsumori. This modification would have been obvious to one of ordinary skill in the art seeking to reduce reagent consumption and to reduce substrate contamination.

Response to Arguments

Applicant's arguments with respect to claims 1,2,4,6 and 8 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jason L. Lazorcik whose telephone number is (571) 272-2217. The examiner can normally be reached on Monday through Friday 8:30 am to 5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Steven Griffin can be reached on (571) 272-1189. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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